

First-principles investigations of oxygen interaction with hydrogen/helium/vacancy irradiation defects in Ti_3AlC_2

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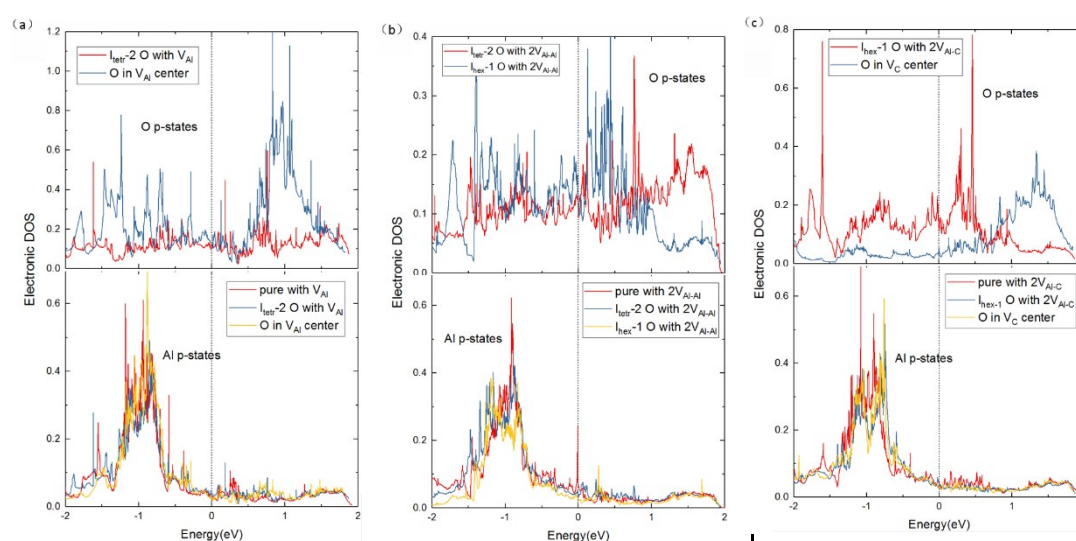


Fig. S1 Local DOS for vacancy nearest-neighbor Al atom and interstitial O atom within (a) V_{Al} monovacancy; (b) $2V_{\text{Al-AI}}$ divacancy; (c) $2V_{\text{Al-C}}$ divacancy.